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BEFORE THE PATENT TRIAL AND APPEAL BOARD

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FUJITSU SEMICONDUCTOR AMERICA, INC.,
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CORPORATION, RENESAS ELECTRONICS AMERICA, INC.,
GLOBALFOUNDRIES U.S., INC., GLOBALFOUNDRIES DRESDEN
MODULE ONE LLC & CO. KG, GLOBALFOUNDRIES DRESDEN
MODULE TWO LLC & CO. KG, TOSHIBA AMERICA ELECTRONIC
COMPONENTS, INC., TOSHIBA AMERICA INC., TOSHIBA
AMERICA INFORMATION SYSTEMS, INC.,
TOSHIBA CORPORATION, and
THE GILLETTE COMPANY,
Petitioners.

V.

ZOND, LLC, Patent Owner

IPR2014-00861¹ Patent 6,806,652 B2

PETITIONER'S REPLY TO PATENT OWNER'S RESPONSE

Claims 18-34

¹ Cases IPR2014-00864, IPR2014-01003, and IPR2014-01066 have been joined with the instant proceeding.



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C. Claims 31-34 are unpatentable over the prior art cited in the instituted grounds.	21
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PETITIONER'S EXHIBIT LIST

June 26, 2015

Exhibit	Description
1101	U.S. Patent No. 6,806,652 ("'652 Patent")
1102	Kortshagen Declaration ("Kortshagen Decl.")
1103	D.V. Mozgrin, <i>et al</i> , <u>High-Current Low-Pressure Quasi-Stationary Discharge in a Magnetic Field: Experimental Research</u> , Plasma Physics Reports, Vol. 21, No. 5, 1995
1104	Wang, U.S. Pat. No. 6,413,382 ("Wang)
1105	D. W. Fahey, et al., High flux beam source of thermal raregas metastable atoms, J. Phys. E; Sci. Insrum., Vol. 13, 1980 ("Fahey")
1106	A. A. Kudryavtsev, <i>et al</i> , <u>Ionization relaxation in a plasma produced by a pulsed inert-gas discharge</u> , Sov. Phys. Tech. Phys. 28(1), January 1983
1107	Chistyakov, U.S. Patent No. 7,147,759
1108	Iwamura, U.S. Patent No. 5,753,886
1109	Röepcke et al, <u>Comparison of Optical Emission Spectrometric</u> <u>Measurements of the Concentration and Energy of Species in Low-pressure Microwave and Radiofrequency Plasma</u> <u>Sources, J. Analytical Atomic Spectrometry</u> , September 1993, Vol. 8, pp. 803-808
1110	J. Hopwood and J. Asmussen, <u>Neutral gas temperatures in a multipolar electron cyclotron resonance plasma</u> , Appl. Phys. Let. 58 (22), 2473-2475 (1991)
1111	G. A. Hebner, Spatially resolved, excited state densities and



	neutral and ion temperatures in inductively coupled argon plasmas, J. Appl. Physics, 80 (5), 2624- 2636 (1996)
1112	Clarenbach, <u>Time-dependent gas density and temperature</u> measurements in pulsed helicon discharges in argon, Plasma Sources Sci. Technol. 12 (2003) 345–357
1113	Plasma Etching: An Introduction, by Manos and Flamm, pp. 185-258, Academic Press (1989) ("Manos")
1114	Campbell, U.S. Pat. No. 5,429,070 ("Campbell")
1115	Affidavit of Mr. Fitzpatrick in Support of Motion for <i>Pro Hac Vice</i> Admission
1116	Stipulation of Dismissals
1117	CONFIDENTIAL BOARD ONLY – Zond TSMC Settlement Agreement
1118	Affidavit of Brett C Rismiller in Support of Petitioner's Motion for <i>Pro Hac Vice</i> Admission
1119	Supplemental Kortshagen Declaration ("Supp. Kortshagen Decl.")
1120	Deposition Transcript of Larry D. Hartsough Ph.D. for U.S. Patent No. 6,806,652 dated May 15, 2015 ("'652 Hartsough Depo. Tr.")



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